



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10B103KB8SFNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 10nF, 50V, ±10%, X7R, 0603

## A. Samsung Part Number

<u>CL</u> <u>10</u> <u>B</u> <u>103</u> <u>K</u> <u>B</u> <u>8</u> <u>S</u> <u>F</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor							
2	Size	0603 (inch o	code)	L: 1.6	± 0.1	mm	W:	$0.8 \pm 0.1$	mm
					_				
(3)	Dielectric	X7R		(8)	Inner e	lectrode	N	li .	
4	Capacitance	<b>10</b> nF			Termin	ation	C	Cu/Ag-Epoxy	1
(5)	Capacitance	±10 %			Plating		S	Sn 100%	(Pb Free)
	tolerance			9	Produc	:t	F	roduct for P	OWER application
6	Rated Voltage	50 V		10	Specia	I	F	Reserved for	future use
7	Thickness	$0.8 \pm 0.1$	mm	11)	Packag	jing	C	Cardboard T	ype, 7" reel

## B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms					
Tan δ (DF)	0.025 max.						
Insulation	10,000Mohm or 500Mohm⋅ <i>µ</i> F	Rated Voltage 60~120 sec.					
Resistance	Whichever is Smaller						
Appearance	No abnormal exterior appearance	Microscope (×10)					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X7R						
Characterisitcs	(From -55℃ to 125℃, Capacitance change shoud be within ±15%)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5℃, 3±0.3sec.					
		(preheating : 80~120 ℃ for 10~30sec.)					
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5 ℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition				
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change: within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.05 max	40±2℃, 90~95%RH, 500+12/-0hrs				
	IR : 500Mohm or 25Mohm ⋅ μF					
	Whichever is Smaller					
High Temperature	Capacitance change: within ±12.5%	With 200% of the rated voltage				
Resistance	Tan δ : 0.05 max	Max. operating temperature				
	IR: 1000Mohm or 50Mohm · μF					
	Whichever is Smaller	1000+48/-0hrs				
Temperature	Capacitance change: within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25℃				
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}$ C				
		5 cycle test				

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5  $^{\circ}$ C , 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.